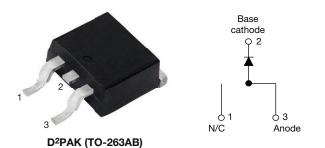




Vishay Semiconductors

High Performance Schottky Rectifier, 16 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	16 A			
V _R	35 V, 45 V			
V _F at I _F	0.57 V			
I _{RM}	40 mA at 125 °C			
T _J max.	150 °C			
E _{AS}	24 mJ			
Package	D ² PAK (TO-263AB)			
Circuit configuration	Single			

FEATURES

- 150 °C T_J operation
- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This VS-MBRB16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	16	А			
V _{RRM}		35/45	V			
I _{FSM}	t _p = 5 μs sine	1800	A			
V _F	16 A _{pk} , T _J = 125 °C	0.57	V			
TJ		-65 to +150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBRB1635-M3	VS-MBRB1645-M3	UNITS	
Maximum DC reverse voltage	V _R	35	45	V	
Maximum working peak reverse voltage	V _{RWM}		40	V	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CON	DITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T_{C} = 134 °C, rated V_{R}	T_{C} = 134 °C, rated V_{R}				
Non-repetitive peak surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse	μs rect. pulse Following any rated load condition and with rated V _{RRM} applied		A		
		Surge applied at rated load condition half wave single phase 60 Hz		150			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3.6 A, L = 3.7 mH		24	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.6	А		

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VS-MBRB1635-M3, VS-MBRB1645-M3

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	16 A	T _J = 25 °C	0.63	v	
Maximum forward voltage drop	VFM (*)	10 A	T _J = 125 °C	0.57		
Maximum instantaneous	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mA	
reverse current	IRM \	T _J = 125 °C	haled DC vollage	40		
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	ge 100 kHz to 1 MHz), 25 °C	1400	pF	
Typical series inductance	L _S	Measured lead from top of terminal to mounting plane		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperatu	re range	TJ		-65 to 150	°C	
Maximum storage temperatur	e range	T _{Stg}		-65 to 175	0	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.50	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0/10	
Approximate weight				2	g	
Approximate weight				0.07	oz.	
minimum				6 (5)	kgf · cm	
Mounting torque maximum				12 (10)	(lbf ⋅ in)	
Marking device	arking device		Case style D ² PAK (TO-263AB)	MBRE MBRE		



VS-MBRB1635-M3, VS-MBRB1645-M3

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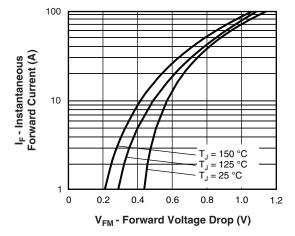


Fig. 1 - Maximum Forward Voltage Drop Characteristics

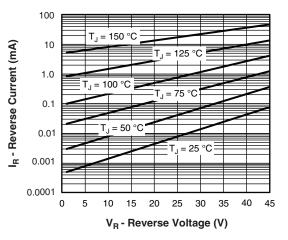


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

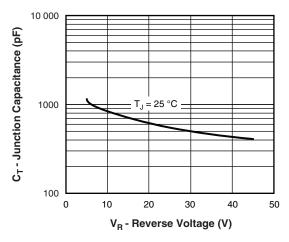
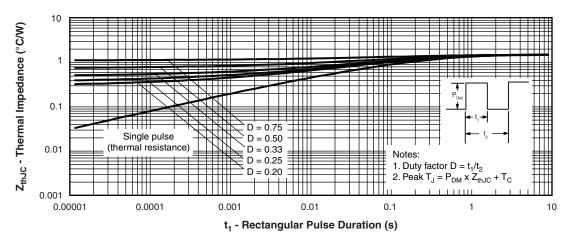


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



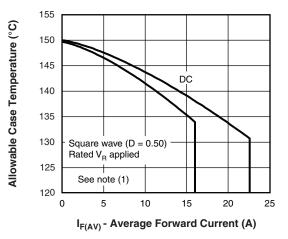


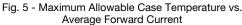
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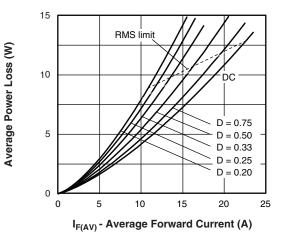


VS-MBRB1635-M3, VS-MBRB1645-M3

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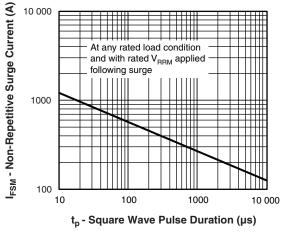


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

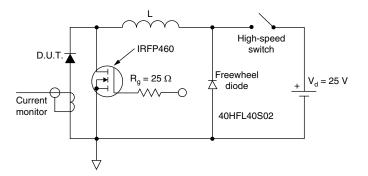


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \ \mathsf{applied} \end{array}$

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ORDERING INFORMATION TABLE

Device code	VS-	MBR	В	16	45	TRL	-M3	
		2	3	4	5	6	7	
	1 - 2 -		-	iconduc art numb		oduct		
	3 -		surface					
	4 - 5 -			ng (16 = le = V _{RR}	,		35 = 45 =	
	6 -	• No	ne = tuk	be			45 =	43 V
		• TR	L = tape	e and re	el (left o	riented)		
		• TR	R = tape	e and re	el (right	oriente	d)	
	7 -	-M3	= halog	gen-free	, RoHS	-complia	ant, and	l termination lead (Pb)-f

ORDERING INFORMATION					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-MBRB1635-M3	50	Antistatic plastic tubes			
VS-MBRB1635TRL-M3	800	13" diameter plastic tape and reel			
VS-MBRB1635TRR-M3	800	13" diameter plastic tape and reel			
VS-MBRB1645-M3	50	Antistatic plastic tubes			
VS-MBRB1645TRL-M3	800	13" diameter plastic tape and reel			
VS-MBRB1645TRR-M3	800	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96164			
Part marking information	www.vishay.com/doc?95444			
Packaging information	www.vishay.com/doc?96424			
SPICE model	www.vishay.com/doc?95407			

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010 BSC		
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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